

Preliminary data sheet

RF Power Amplifier

RF0011000-50 bi

This solid state power amplifier is designed for reliable, trouble-free service. It operates in a class A/AB and includes RF protection circuits, cooling installations and 230 V AC power supply. The amplifier is accommodated in a 19" system housing.

Features :

- * 55 to 60 Watts saturated output power for band 1 (10 KHz - 220 MHz)
- * 50 to 60 Watts saturated output power for band 2 (200 MHz -1000 MHz)
- * 40 dB minimum gain
- * Electronic Attenuator in option
- * one input , one output switching manual or remote
- * Temperature protection

Applications :

- * Test Bench
- * Field Test
- * Instrumentation

Specifications

Characteristics	Data	Units
Frequency range band 1	0.01 - 220	MHz
band 2	200 - 1000	MHz
RF output power CW		
Typ. band1/band2	60/60	W
Min	50/60	W
Class	A/AB	
Power gain	47/47	dB
Flatness typ	+/-2,5 dB	dB
Input power for rated output power	0	dBm
Max. input power	7	dBm
In / Out impedances nom.	50	Ohms
Input VSWR	2 : 1	
Load VSWR for rated output power	up to 1.5 : 1	
VSWR mismatch	infinite	
Protection circuits	Over temperature	
Harmonics typ.	-15	dBc
Spurious typ.	-60	dBc
Modulation capability	100	%
Noise Figure typ.	10	dB
Intercept point 3 rd Order min.		dBm
RF connectors	N female	
Cooling	Forced air (self-contained fans)	
Operating temperature Range	0 °C ... + 40	° C
Power Supply	230 AC +/- 10 % ,47-63 Hz	V
Dimensions (W x L x H)	4 U 19" Rack 490 x 460 x 172	mm

All data at room temperature + 22 °C, into 50 Ohms, subject to change without notice

Made in European Union

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